

APTD3216P3C-P22  
3.2 x 1.6 mm Phototransistor

DESCRIPTION

- Made with NPN silicon phototransistor chips

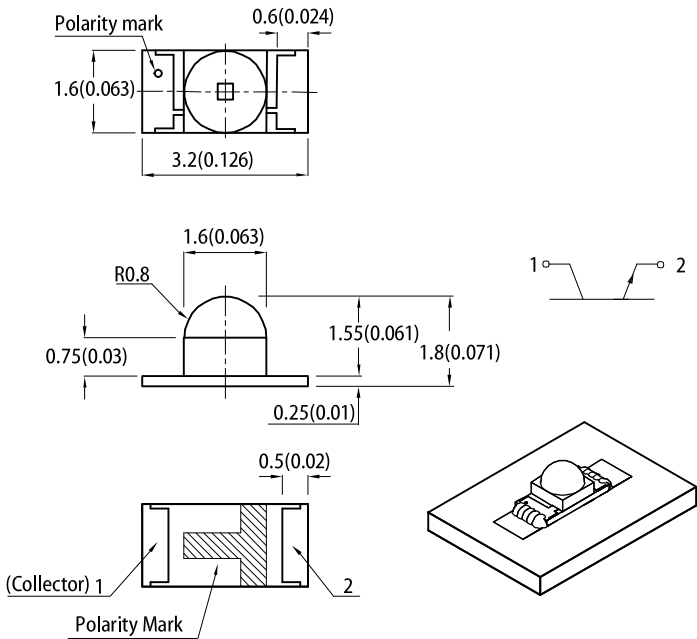
FEATURES

- 3.2 mm x 1.6 mm SMD LED, 1.8 mm thickness
- Mechanically and spectrally matched to infrared emitting LED lamp
- Package matched with IR emitter APTD3216F3C-P22
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- Water clear lens
- RoHS compliant

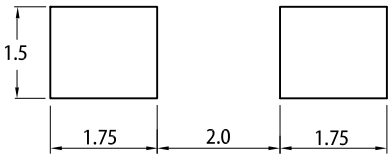
APPLICATIONS

- Infrared applied systems
- Optoelectronic switches
- Photodetector control circuits
- Sensor technology

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN  
(units : mm; tolerance : ± 0.1)



- Notes:
- All dimensions are in millimeters (inches).
  - Tolerance is ±0.2(0.008") unless otherwise noted.
  - The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
  - The device has a single mounting surface. The device must be mounted according to the specifications.

ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C

Parameter	Max.Ratings	Units
Collector-to-Emitter Voltage	30	V
Emitter-to-Collector Voltage	5	V
Power Dissipation at(or below) 25°C Free Air Temperature	100	mW
Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +85	°C

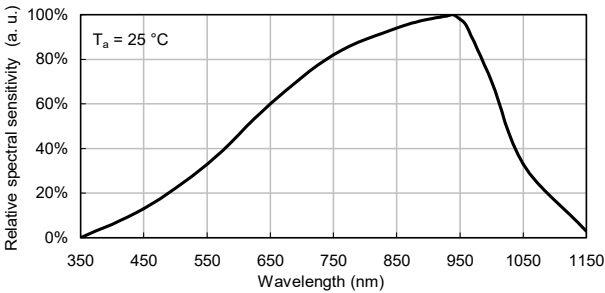
Note:  
1. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Collector-to-Emitter Breakdown Voltage	V <sub>BR CEO</sub>	30	-	-	V	I <sub>C</sub> = 100μA E <sub>e</sub> = 0mW/cm <sup>2</sup>
Emitter-to-Collector Breakdown Voltage	V <sub>BR ECO</sub>	5	-	-	V	I <sub>E</sub> = 100μA E <sub>e</sub> = 0mW/cm <sup>2</sup>
Collector-to-Emitter Saturation Voltage	V <sub>CE (SAT)</sub>	-	-	0.8	V	I <sub>C</sub> = 2mA E <sub>e</sub> = 20mW/cm <sup>2</sup>
Collector Dark Current	I <sub>CEO</sub>	-	-	100	nA	V <sub>CE</sub> = 10V E <sub>e</sub> = 0mW/cm <sup>2</sup>
Rise Time(10% to 90%)	t <sub>r</sub>	-	15	-	μS	V <sub>CE</sub> = 5V I <sub>C</sub> = 1mA R <sub>L</sub> = 1000Ω
Fall Time(90% to 10%)	t <sub>f</sub>	-	15	-	μS	
On State Collector Current	I <sub>(ON)</sub>	0.4	1	-	mA	V <sub>CE</sub> = 5V E <sub>e</sub> = 1mW/cm <sup>2</sup> λ = 940nm
Range of Spectral Bandwidth	λ <sub>0.1</sub>	420	-	1120	nm	-
Wavelength of Peak Sensitivity	λ <sub>p</sub>	-	940	-	nm	-

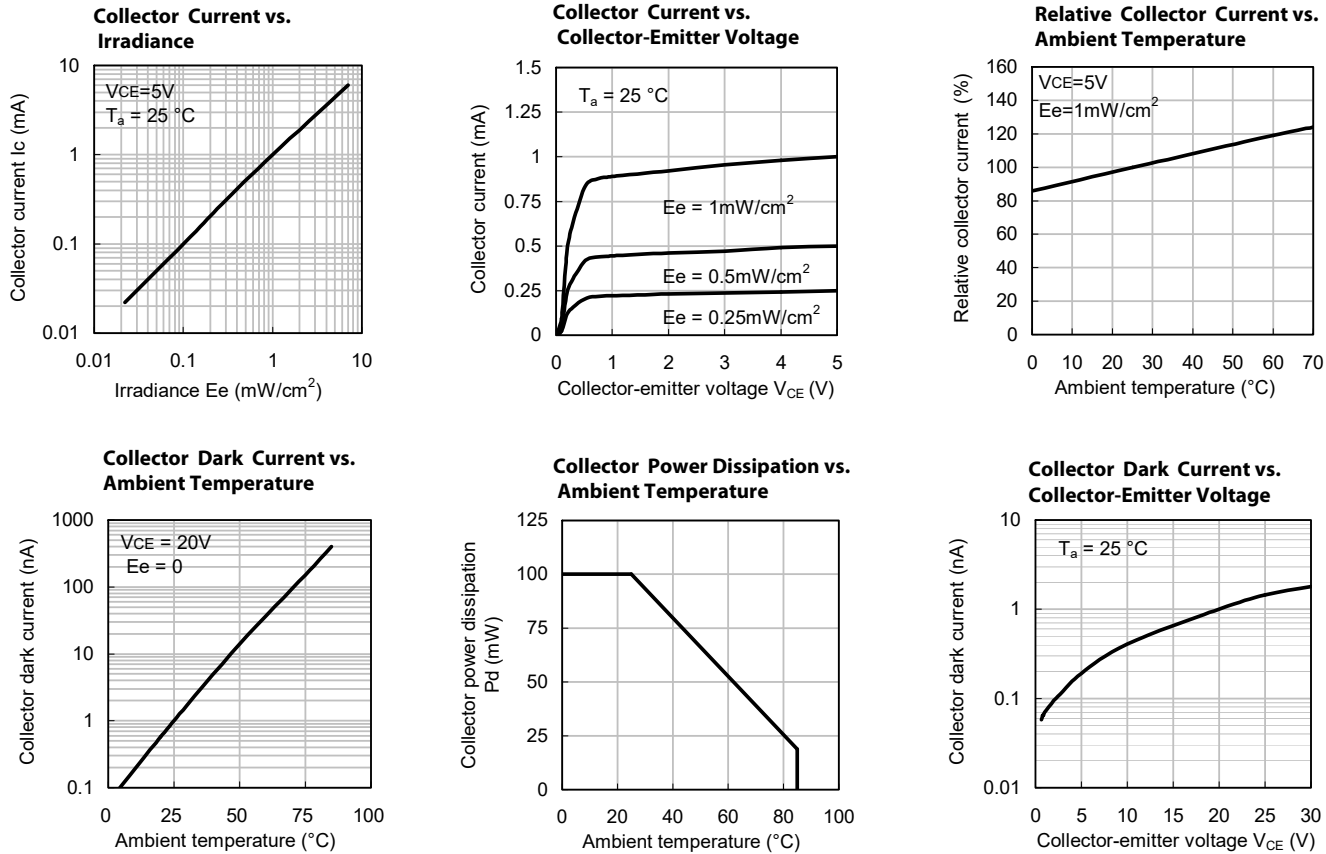
TECHNICAL DATA

RELATIVE SPECTRAL SENSITIVITY vs. WAVELENGTH

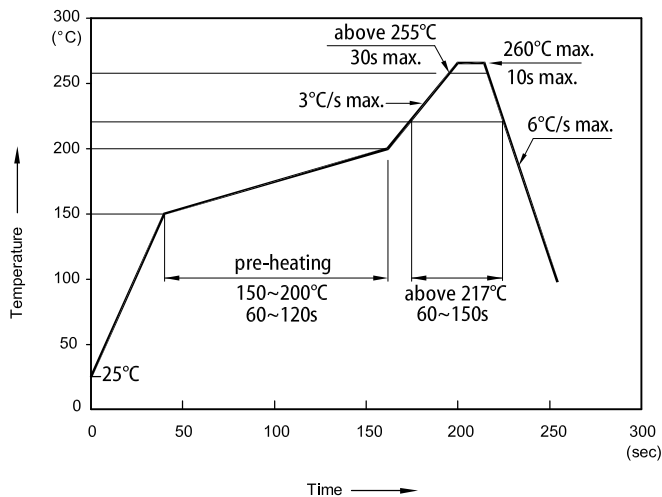


TECHNICAL DATA

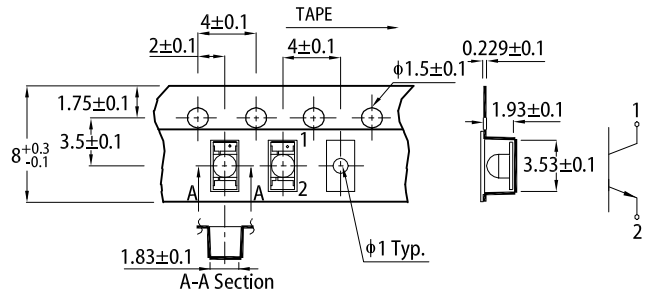
PHOTOTRANSISTOR



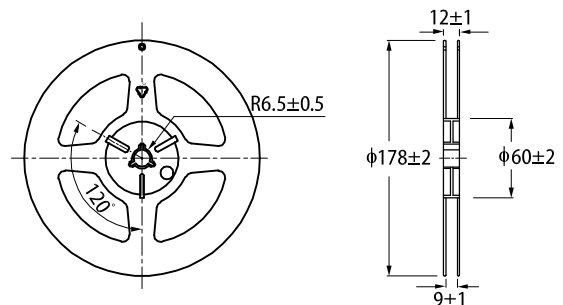
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units : mm)

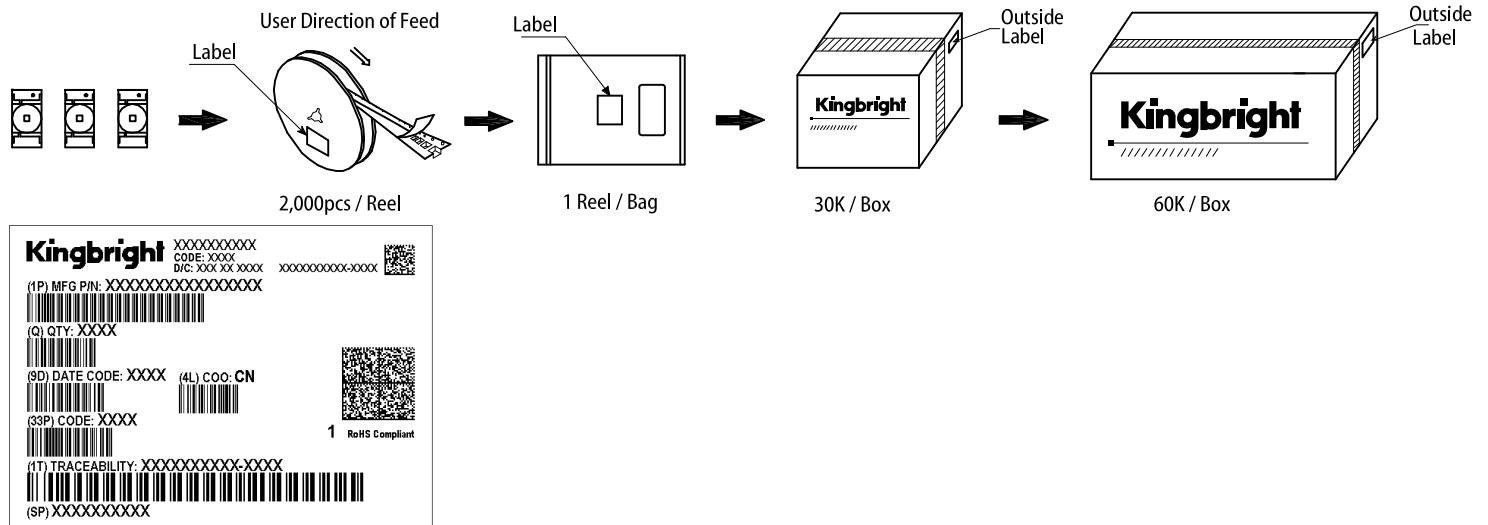


REEL DIMENSION (units : mm)



- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
  2. The maximum number of reflow soldering passes is 2 times.
  3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

## PACKING & LABEL SPECIFICATIONS



## PRECAUTIONARY NOTES

1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
3. When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
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